INTEGRATED CIRCUITS

DATA SHEET

74LVC02AQuad 2-input NOR gate

Product specification
Supersedes data of 1997 Aug 11
IC24 Data Handbook







Philips Semiconductors Product specification

Quad 2-input NOR gate

74LVC02A

FEATURES

- Wide supply range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- Inputs accept voltages up to 5.5V
- CMOS low power consumption
- Direct interface with TTL levels
- 5-volt tolerant inputs, for interfacing with 5-volt logic

DESCRIPTION

The 74LVC02A is a high performance, low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 V/5 V environment.

The 74LVC02A provides the 2-input NOR function.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} t _{PLH}	Propagation delay nA, nB to nY	C _L = 50 pF; V _{CC} = 3.3 V	2.8	ns
C _I	Input capacitance		5.0	pF
C_{PD}	Power dissipation capacitance per gate	Notes 1 and 2	28	pF

NOTES:

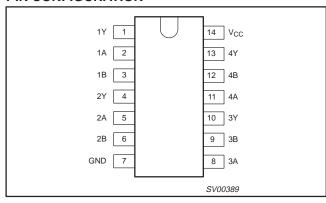
- 1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW)
 - $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:
 - f_i = input frequency in MHz; C_L = output load capacity in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V;

 - $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$
- 2. The condition is $V_I = GND$ to V_{CC} .

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40°C to +85°C	74LVC02A D	74LVC02A D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +85°C	74LVC02A DB	74LVC02A DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC02A PW	74LVC02APW DH	SOT402-1

PIN CONFIGURATION



PIN DESCRIPTION

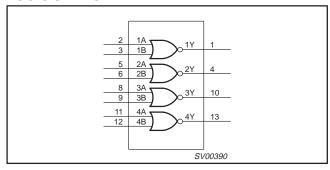
PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 4, 10, 13	1Y – 4Y	Data outputs
2, 5, 8, 11	1A – 4A	Data inputa
3, 6, 9, 12	1B – 4B	Data inputs
7	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

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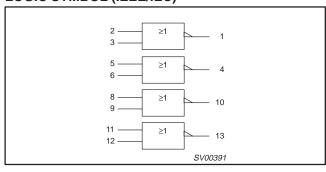
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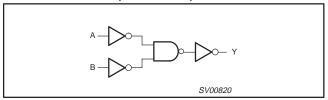
LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



LOGIC DIAGRAM (ONE GATE)



FUNCTION TABLE

INPU	OUTPUTS					
nA	nA nB					
L	L	Н				
L	Н	L				
Н	L	L				
Н	Н	L				

NOTES:

H = HIGH voltage level L = LOW voltage level

RECOMMENDED OPERATING CONDITIONS

CVMDOL	DADAMETER	CONDITIONS	LIM	LIMITS				
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT			
V _{CC}	DC supply voltage (for max. speed performance)		2.7	3.6	V			
V _{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V			
VI	DC Input voltage range		0	5.5	V			
Vo	DC output voltage range		0	V _{CC}	V			
T _{amb}	Operating ambient temperature range in free-air		-40	+85	°C			
t _r , t _f	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7V$ $V_{CC} = 2.7 \text{ to } 3.6V$	0	20 10	ns/V			

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74LVC02A

ABSOLUTE MAXIMUM RATINGS¹

Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage (for max. speed performance)		-0.5 to +6.5	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
V _I	DC input voltage	Note 2	-0.5 to +5.5	V
lok	DC output diode current	$V_{O} > V_{CC}$ or $V_{O} < 0$	±50	mA
Vo	DC output voltage	Note 2	-0.5 to $V_{CC} + 0.5$	V
Io	DC output source or sink current	$V_O = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		± 100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

DC CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

			ι				
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	UNIT			
			MIN	TYP ¹	MAX		
	LUCI I loval Innut valtage	V _{CC} = 1.2V	V _{CC}			\ \	
V _{IH}	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0			1 °	
	LOW level length voltage	V _{CC} = 1.2V			GND	V	
V _{IL}	LOW level Input voltage	V _{CC} = 2.7 to 3.6V			0.8	1 °	
		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -12mA$	V _{CC} -0.5				
	LUCI Lloyal autout valtage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu\text{A}$	V _{CC} -0.2	V _{CC}] ,	
V _{OH}	HIGH level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -18\text{mA}$	V _{CC} -0.6]	
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -24$ mA	V _{CC} -0.8				
		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 12$ mA			0.40		
V _{OL}	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$			0.20	V	
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 24$ mA			0.55	1	
l _l	Input leakage current	V _{CC} = 3.6V; V _I = 5.5V or GND		±0.1	±5	μА	
Icc	Quiescent supply current	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND; $I_O = 0$		0.1	10	μΑ	
Δl _{CC}	Additional quiescent supply current per input pin	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$; $I_O = 0$		5	500	μА	

NOTES:

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{1.} All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

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AC CHARACTERISTICS

GND = 0 V; $t_r = t_f \leq 2.5 \text{ ns}$; $C_L = 50 \text{ pF}$

			LIMITS							
SYMBOL PARAMETER		WAVEFORM	VAVEFORM V _{CC} =			V _{CC} = 2.7V			V _{CC} = 1.2V	UNIT
			MIN	TYP ¹	MAX	MIN	TYP ¹	MAX	TYP	
t _{PHL} /t _{PLH}	Propagation delay nA, nB to nY	Figures 1, 2	1.5	2.8	4.6	1.5	3.2	5.6	11	ns

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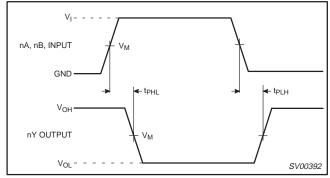
NOTE:

AC WAVEFORMS

 V_{M} = 1.5 V at $V_{CC}\,\geq\,2.7$ V

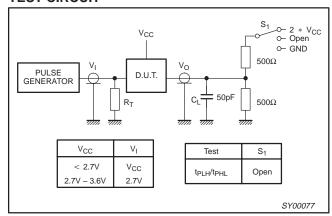
 V_{M} = 0.5 • V_{CC} at V_{CC} < 2.7 V

 $V_{\mbox{\scriptsize OL}}$ and $V_{\mbox{\scriptsize OH}}$ are the typical output voltage drop that occur with the output load.



Waveform 1. Input (nA, nB) to output (nY) propagation delays.

TEST CIRCUIT



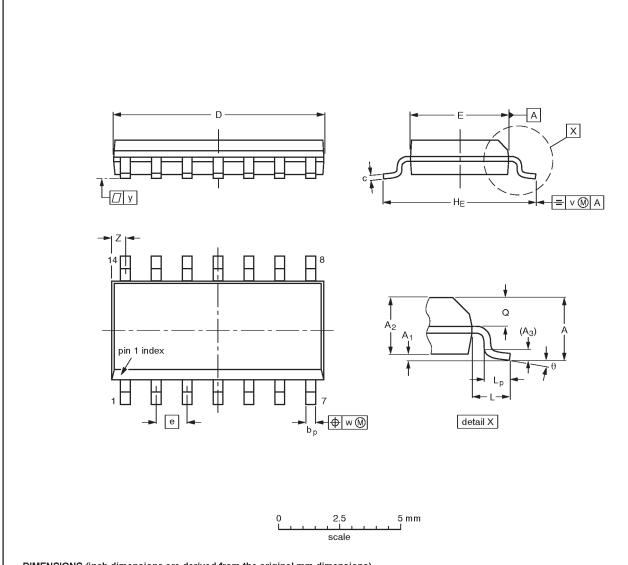
Waveform 2. Load circuitry for switching times.

^{1.} These typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	Α1	A ₂	Α3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.0098 0.0039		0.01		0.0098 0.0075	0.35 0.34	0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

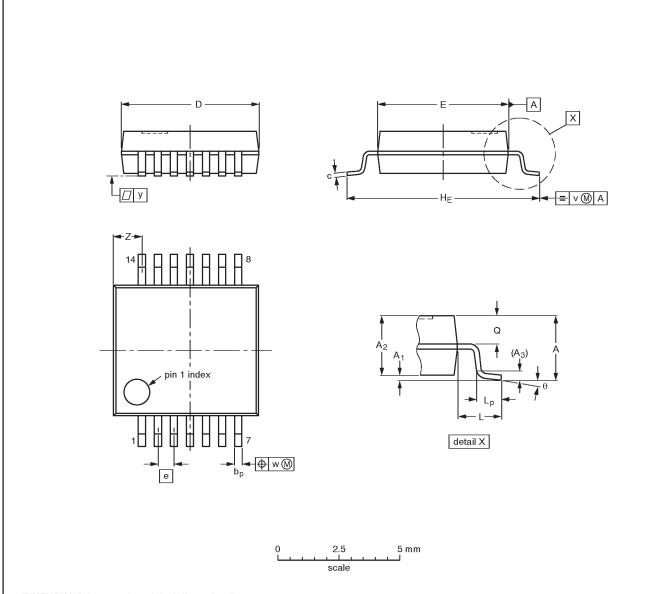
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT108-1	076E06\$	MS-012AB			91-08-13 95-01-23	

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	c	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

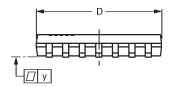
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

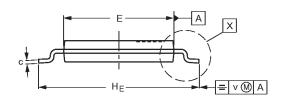
OUTLINE		EUROPEAN	ISSUE DATE				
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT337-1		MO-150AB				95-02-04 96-01-18	

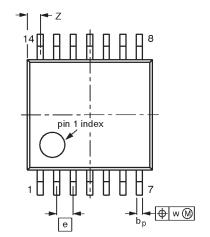
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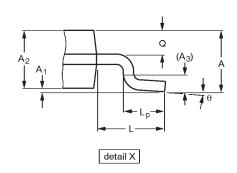
TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

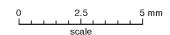
SOT402-1











DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	c	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT402-1		MO-153				-94-07-12 95-04-04	

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NOTES

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DEFINITIONS						
Data Sheet Identification	Product Status	Definition				
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.				
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.				
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.				

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print code Date of release: 05-96

Document order number: 9397-750-04477

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